NSN 5961-00-443-8230

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-443-8230

Inclosure Material:

Metal

Overall Length:

0.375 inches

Overall Width:

1.050 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 breakdown voltage, collector-to-base, emitter open and 400.0 breakdown voltage, collector-to-emitter, base open and 5.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0